



CHENMKO ENTERPRISE CO.,LTD

Lead free devices

**SURFACE MOUNT
SWITCHING DIODE**

VOLTAGE 75 Volts CURRENT 150 mAmpere

LL4448PT

APPLICATION

- * Ultra high speed switching

FEATURE

- * Small surface mounting type. (MINI-MELF)
- * High speed. ($T_{RR}=4.0\text{ nSec Typ.}$)
- * Suitable for high packing density.
- * Maximum total power dissipation is 300mW.
- * Peak forward current is 500mA.

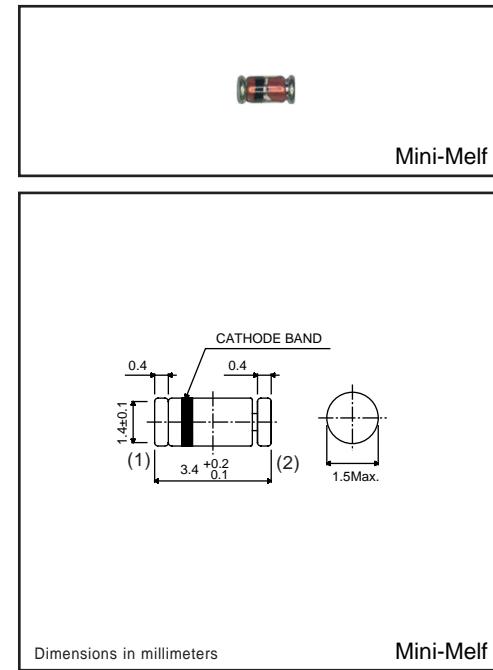
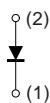
CONSTRUCTION

- * Silicon epitaxial planar



Mini-Melf

CIRCUIT



Dimensions in millimeters

Mini-Melf

MAXIMUM RATINGS (At $T_A = 25^\circ\text{C}$ unless otherwise noted)

RATINGS	SYMBOL	LL4448PT	UNITS
Maximum Non-Repetitive Peak Reverse Voltage	VRM	100	Volts
Maximum Repetitive Peak Reverse Voltage Maximum Working Peak Reverse Voltage Maximum DC Blocking Voltage	VR _{RRM} VR _{WM} V _{DC}	75	Volts
Maximum RMS Voltage	VRMS	53	Volts
Maximum Average Forward Rectified Current	Io	150	mAmps
Repetitive Peak Forward Current	IfRM	500	mAmps
Peak Forward Surge Current at 1uSec. @1.0uSec	IfSM	1.0 2.0	Amps
Typical Junction Capacitance between Terminal (Note 1)	C _J	4.0	pF
Maximum Reverse Recovery Time (Note 2)	trr	4.0	nSec
Maximum Thermal Resistance	R _{θJA}	350	°C/W
Maximum Operating and Storage Temperaturd Range	T _{J,TSTG}	-65 to +175	°C

ELECTRICAL CHARACTERISTICS (At $T_A = 25^\circ\text{C}$ unless otherwise noted)

CHARACTERISTICS	SYMBOL	LL4448PT	UNITS
Maximum Instantaneous Forward Voltage @ If= 5.0 mA @ If= 100 mA	V _F	0.72 1.0	Volts
Maximum Average Reverse Current V _R = 20V @T _J =25°C V _R = 75V @T _J =25°C V _R = 20V @T _J =150°C	I _R	25nA 5.0 50	uAmps

NOTES : 1. Measured at 1.0 MHz and applied reverse voltage of 0 volts.

2. Measured at applied foward current of 10 mA, reverse current of 1.0 mA, Reverse voltage of 6.0 volts and R_L= 100 ohms.

3. ESD sensitive product handling required.

2003-11

RATING CHARACTERISTIC CURVES (LL4448PT)

FIG. 1 - FORWARD CHARACTERISTICS

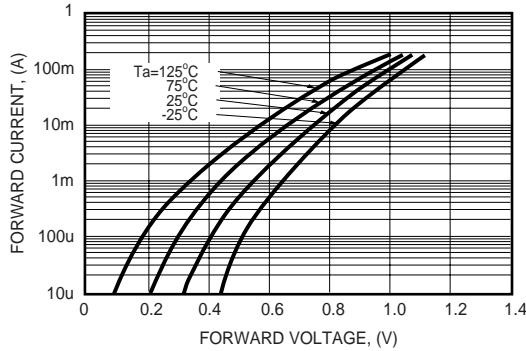


FIG. 2 - REVERSE CHARACTERISTICS

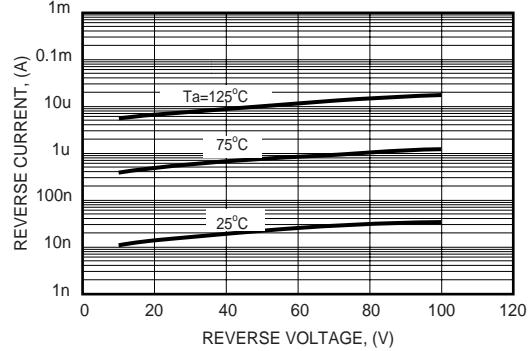


FIG. 3 - TYPICAL JUNCTION CAPACITANCE

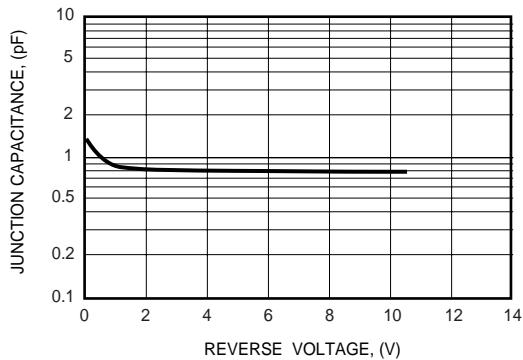


FIG. 4 - REVERSE RECOVERY TIME CHARACTERISTICS

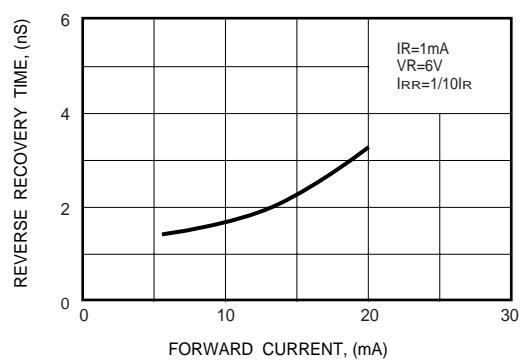


FIG. 5 - MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

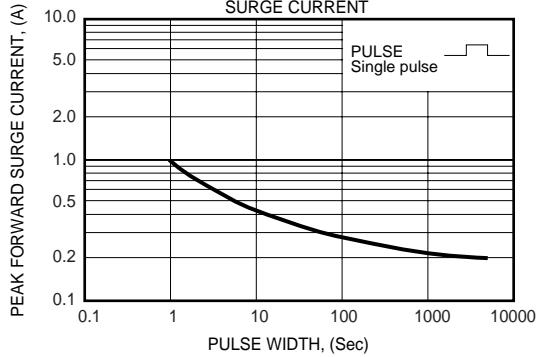


FIG. 6 - REVERSE RECOVERY TIME MEASUREMENT CIRCUIT

